PCN Number: 202		2022	220722001.2				Date:	September 26, 2022	
Title:	Qualification o	of new	Proc	cess Technology ar	nd Die Ch	ange f	or select	DRV5013 devices	
Customer	Contact:		<u>PCN</u>	Manager		Dept:		Quality Services	
Proposed	1 <sup>st</sup> Ship Date:		March 26, 2023 Samplaccep			-		October 26, 2022*	
*Sample requests received after October 26, 2022 will not be supported.									
Change Ty	/pe:								
Assembly Site				Assembly Process		Assembly Materials			
Desig	n			Electrical Specific	ation		Mechanical Specification		
Test Site				Packing/Shipping/Labeling			Test Process		
Wafe	r Bump Site		Wafer Bump Material				Wafer Bump Process		
Wafe	r Fab Site		Wafer Fab Materials				Wafer Fab Process		
				Part number chan	ge				
	Notification Details								

#### **Description of Change:**

Texas Instruments is pleased to announce the qualification of a new process technology (LBC9) in RFAB and die change as listed below in the product affected section.

Fab Site	Current Process Technology	New Process Technology
RFAB	LBC8	LBC9

In support of the qualification of the new process technology, the devices will undergo a die change.

Qual details are provided in the Qual Data Section.

**Reason for Change:** 

Continuity of supply

Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative): None.

Changes to product identification resulting from this PCN:

The Die Revision will change as shown in the table and sample label below:

Current	New
Die Rev [2P]	Die Rev [2P]
A0, A1	В

Sample product shipping label (not actual product label)



Product Affected:			
DRV5013ADEDBZRQ1	DRV5013ADEDBZTQ1	DRV5013ADQDBZRQ1	DRV5013ADQDBZTQ1
DRV5013FAEDBZRQ1			

## Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines) DRV5013 Refresh Grade 1 Automotive DBZ in TFME Approve Date 22-SEPTEMBER-2022

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: <u>DRV5013ADQDBZRQ1</u>	QBS Reference: <u>DRV5015A2EDBZRQ1</u>	QBS Reference: <u>DRV5015A3EDBZRQ1</u>
Test Group	A - Acce	elerated Enviror	nment St	ress Tes	sts					
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL1 260C	1 Step	1/0/0	1/0/0	2/0/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	1/77/0	1/77/0	2/156/0
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	-	1/77/0	2/154/0
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	1/77/0	-	-
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	1/77/0	1/77/0	2/154/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-	1/5/0	1/5/0	1/5/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	1/45/0	-	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	1000 Hours	-	-	1/77/0
Test Group	B - Acce	elerated Lifetime	e Simula	tion Tes	ts					
HTOL	В1	JEDEC JESD22- A108	1	77	Life Test	125C	1000 Hours	1/77/0	-	-
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	150C	1000 Hours	-	-	3/231/0
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	150C	48 Hours	-	-	2/1600/0
Test Group	C - Pack	age Assembly	Integrity	Tests						
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device	QBS Reference	QBS Reference
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	3/90	1/30/0	1/30/0
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	1/6/0	1/6/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	1/3/0	-	-
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	2000 Volts	-	1/3/0	1/3/0
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	5000 Volts	-	1/3/0	1/3/0
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	1/3/0	-	-
Test Group	p E - Eleci	trical Verificatio	n Tests							
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	p D - Die F	abrication Relia	ability Te	sts						
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	1/10/0	-	-
SD	СЗ	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	1/15/0
SD	C3	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-	-	1/15/0

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

• The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

• The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

• The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

#### Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I) : -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- Room/Hot/Cold : HTOL, ED
- Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

# Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines) DRV5013 Refresh Grade 0 Automotive DBZ in TFME Approve Date 22-SEPTEMBER-2022

### Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

		-		- 10 -	a, ca asi in		1013 / 1	otal sample size			
Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: DRV5013ADEDBZRQ1	Qual Device: DRV5013FAEDBZRQ1	QBS Reference: DRV5015A2EDBZRQ1	QBS Reference: DRV5015A3EDBZRQ1
Test Group	A - Acce	lerated Enviror	nment St	ress Tes	sts					·	
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL1 260C	1 Step	1/0/0	-	1/0/0	2/0/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	1/77/0	-	1/77/0	2/156/0
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	-	-	1/77/0	2/154/0
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	1/77/0	-	-	-
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycling	-65C to 150C	1654 Cycles	1/77/0	-	1/77/0	2/154/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post TC ball Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Units	1/5/0	-	1/5/0	1/5/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	2000 Hours	1/45/0	-	-	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	1000 Hours	-	-	-	1/77/0
Test Group	B - Acce	lerated Lifetime	e Simula	tion Tes	ts						
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	150C	1000 Hours	1/77/0	-	-	3/231/0
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	150C	48 Hours	-	-	-	2/1600/0
Test Group	C - Pack	age Assembly	Integrity	Tests							
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-	-
SD	СЗ	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-		-	1/15/0
SD	СЗ	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	-	1/15/0
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	1/10/0	-	-	-

Test Group	D - Die F	abrication Relia	ability Te	sts							
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	rical Verificatio	n Tests								
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	1/3/0		-	
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	5000 Volts	-	-	1/3/0	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	2000 Volts	-	-	1/3/0	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	1/3/0	-	-	-
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	-	1/6/0	1/6/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	2/60/0	1/30/0	1/30/0	1/30/0
Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device	Qual Device	QBS Reference	QBS Reference

• Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

• The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

#### Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
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E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- Room/Hot/Cold : HTOL, ED
- Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

For questions regarding this notice, e-mails can be sent to the contact shown below or your local Field Sales Representative.

Location	E-Mail
WW PCN Team	<u>PCN ww admin team@list.ti.com</u>

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